Bipolar spin Iter in a quantum dot molecule

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We show that the tunable hybridization between two lateral quantum dots connected to non-magnetic current leads in a hanging-dot' con guration that can be used to implement a bipolar spin liter. The competition between Zeeman, exchange interaction, and interdot tunneling (molecular hybridization) yields a singlet-triplet transition of the double dot ground state that allows spin litering in Coulomb blockade experiments. Its generic nature should make it broadly useful as a robust bidirectional spin polarizer.

Controlling the spin of electrons in mesoscopic systems is an important task in spintronic devices, as well as in the fundamental understanding of spin relaxation and coherence. Experiments using diluted magnetic sem iconductors (DMS) heterostructures have reported excellent polarization values (90%). Spin-polarized currents have been observed using ferrom agnetic leads in sem iconductor quantum dots.3 Pioneering studies have also appeared recently where dierent spin-lter and polarization m easurem ents have been described where no polarization of the leads is needed. The original proposal of Recher et al.4 { to produce a spin-polarized current using the Zeem an e ect in a quantum dot with odd num ber of electrons { has been recently implemented in beautiful experiments by Hanson et al.⁵ They report nearly pure (99%) spin collection for spin-unpolarized leads, a reection of the large orbital energy separation achieved in their sm all quantum dots. M oreover, they can sw iffly ip the spin polarization (a bipolar' lter) by changing the charge state of the single dot. Bidirectional spin ltering making clever use of spin coherence and magnetic focusing was reported by Potok et al.,7,8 who achieved very good spin (70%) polarization at moderate applied elds (6T parallel to the plane of the dot).

Spin-blockade in double quantum dots (DQD) connected in series (sequentially) and coupled via tunneling has also been studied by Johnson et al. using transport measurements and charge sensing with quantum point contacts. They observe current rectication due to the singlet-triplet spin-blockade mechanism in the DQD. Coulomb-and spin-blockade spectroscopy studies in spin sensitive experiments were also realized recently in a two-levelDQD molecule. 11

In this letter we show theoretically that a bipolar spin liter can be implemented at moderate elds by producing a singlet-triplet transition of the DQD ground state. This transition is obtained solely by tuning the hybridization (hopping) between the two quantum dots in the molecule, achieved by varying the coupling via the quantum point contact connecting the dots. The DQD is connected to

non-m agnetic leads via only one of the dots, in a hanging dot' con guration (Fig. 1a). It is shown that the competition between Zeem an energy and the elective superexchange' interaction results in lower energy for the singlet conguration for large enough interdot tunneling and even electron number. This in turns gives rise to a natural spin selectivity, fully tunable by appropriate electrical gating of the structure. The elect is shown to arise in both the linear (low bias) and non-linear regimes of transport at low temperatures.

W em odel the coupled D Q D m olecule as a single coherent system , where the quantum dots are assumed small enough so as to have only one relevant orbital energy level on each dot with gate-controlled on-site energies $_{\rm i}$, (i = 1;2). The conducting dot in the molecule (dot 2 in Fig. 1a) is weakly coupled to non-magnetic reservoirs.

The H am iltonian of the DQD molecule is H = H $_0$ + H $_{\rm int}$, where

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$$H_{int} = U \begin{bmatrix} X & & & & \\ & \hat{n}_{i;"} \hat{n}_{i;\#} + \frac{1}{2} & V & \frac{J}{2} & \hat{n}_{i} \hat{n}_{j} \\ & & X & & \\ J & S_{i} & S_{j} + \frac{1}{2} & & & \\ & & & i_{i} \hat{n}_{j} & & \\ & & & & z \hat{c}_{i; j}^{V} (z) & \circ \hat{c}_{i; j} \circ ; (2) \end{bmatrix}$$

where $c_{i;}^{y}$ is the creation operator for electrons on each dot i with spin (";#), t describes the interdot orbital hybridization, which can be tuned in a typical setup by voltages on the quantum point contact de ning the connection between dots. In (2), U is the double occupation charging energy, V is the interdot C oulomb interaction, J gives the interdot exchange interaction (with J > 0)¹², and nally $z^{(i)} = j j j_B B_z^{(i)}$ is the Zeem an energy splitting for dot i in a local magnetic eld $B_z^{(i)}$. Such local splitting could be produced for instance by nanoscale magnetic disks of ferrom agnetic material, as suggested

recently. 14 . Spin-orbit coupling is also introduced as in [15] but its strength is typically small ($t_{\rm SO}$ < 0:1t), and does not appreciably a ect our results and conclusions.

We are interested in the elective low-occupation of the DQD, so that the relevant basis (levels close to the Ferm i energy) consists of a few states for N = 0;1 and 2 electrons.

Consider now the case with symmetrical QD's ($_1$ = $_{2}$ =), and hom ogeneous magnetic eld, $_{z}^{(1)}$ = $_{z}^{(2)}$ = z. A non-zero magnetic eld breaks the spin degeneracy in the DQD. The energy spectrum for N = 1 is given by $E_{1;2}^{(1)} = t_z=2$, and $E_{3;4}^{(1)} = +t_z=2$, with (nonnorm alized) eigenstates $j_1i = j$ ";0i+ $j_2i = j$ # $0i + 0; #i, j_3i = 0; "i j"; 0i, and j_4i = 0; #i j#; 0i,$ respectively. For two electrons in the DQD, the magnetic eld breaks the degeneracy of the triplet states Ji = j" ;#i+ j#;"i, T_+ i= j";"i and T i= j#;#i. The com petition between the Zeem an energy, the exchange and the interdot hybridization strength produces a singlet-triplet transition for the ground state, as shown schematically in Fig. 1b. For a xed (large enough) magnetic eld and $t < t_c$, the ground state is the triplet $j\Gamma_+ i = j";"i$ with energy $E_1^{(2)}$ (t < t_c) = 2 + V $_{\rm z}$ J, while for $t > t_c$ the ground state is the singlet con guration \mathfrak{F}_{\circ} i = \mathfrak{j} ";#i \mathfrak{j} #;"i+ $(\mathfrak{j}$ "#;0i \mathfrak{p} \mathfrak{p} ;#"i),where is t-dependent, = 4t= $(U \ V \ J + \ 16$ t² + $(U \ V \ J)^2)$. The singlet has a peld-independent energy $E_1^{(2)}$ (t> t_c) = 2 + $\frac{1}{2}$ (U + V + J $\frac{1}{2}$ (t+ $\frac{1}{2}$ (U + V + J). The transition occurs then at t = t_c = $\frac{1}{2}$ (2J + $\frac{1}{2}$) (U V + $\frac{1}{2}$ + J). The conductance per spin in the low bias regime is given by 16,17

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$$(T; V_g) = \frac{e^2}{k_B T} \sum_{n=1}^{N_{X_a \times X}} \frac{\sum_{n=1}^{L} R_n}{\sum_{n=1}^{R} + R_n} P_n^{eq};$$

 $[1 ext{ } f_{FD} ext{ } (E_n; ext{ } E_{n-1}; ext{ })] ext{ } (3)$

where $_{\rm n}$ = S is the tunneling rate involving lead for an electron with spin . measures the tunneling amplitude from /to the leads, while S = ${\rm jn}$; ${\rm jr}^{\rm y}$ jn 1; ${\rm ij}^{\rm p}$ is the spectral weight whereby the DQD goes from a quantum state with n 1 electrons to a quantum state with n electrons (see references for details). This conductance expression assumes weak coupling to the leads and su ciently high temperatures that one can neglect the K ondo e ect due to correlations with the reservoir electrons. 20

The only non-zero contributions to the spectral weights involving the DQD ground state, for the N : 0 ! 1 transition are $S_{11}^{\;\;;"}= h_1 j_{-}^{v} p j_{-}^{v} j_$

Figure 2 shows the conductance through the DQD molecule as function of the gate voltage $V_{\rm g}\,$ for vari-

ous interdot tunneling (hybridization) strengths t. The Coulomb interdot energy is set here to V = 0.24 m eV, with $_1 = _2 = 0.25 \text{m eV}$, U = 1 m eV, 21 J = 0.01 m eVfor the DQD sizes of interest, z = 0.03m eV, and symmetrical tunneling to/from the leads 0.25 eV. At low interdot tunneling, the conductance is completely spin polarized for the transitions N:0! 1 and 1! 2 in the DQD. Since transport in this low bias regime is determined by the ground state, the spin-up polarized conductance dem onstrates that the Zeem an energy dom inates at these param eters and the conductance accesses the triplet ground state, as one would expect. However, as the interdot tunneling increases, the electrons delocalize, increasing the hybridization and making the singlet con guration the ground state of the DQD. Correspondingly, the second conductance peak at higher gate voltage, for the transition N :1! 2, has a reversed spin character with respect to the rst. The conductance changes from spin up polarization at weak coupling (t < 0:08) to spin down polarization at higher t values (t 0:12), with a crossover point a $t_c = 0:1m \text{ eV}$, where both spin conductances are nearly identical. The large interdot hybridization results in the switch of the spin polarization for the current through the DQD, resulting in a bipolar spin liter with high e ciency (up to 80%); all by just adjusting the quantum point contact between dots.

The bipolar spin liter is robust to detuning of the onsite energies = $_2$ $_1$. For example, while xing $_2$ and varying $_1$ via local gates on each dot, the bipolar function is basically una ected for $_z$ $_j$ $_j$ except for slight shifts in the overall position of the Coulomb blockade peaks (not shown). In contrast, the spin liter e ect can be strongly modiled by large asymmetries in the local Zeem an splitting. This exibility might be useful if one controls the local elective eld in the system, via magnetic disks placed in close proximity to the dots, or local gating to a ect the individual dot g-factors, for example.

We have also explored the DQD in the non-linear regim e of transport. The spin dependent current is calculated by generalizing Eq. (3) of Ref. 18. Figure 3 shows the spin polarization current map $(I_n I_{\sharp})$ in the V_{sd} V_{g} plane, where V_{sd} is the source-drain bias. Panel (a) shows a net electron spin current through the DQD for relatively large tunneling strength, t = 0.15 m eV, whereas lower panel (b) depicts the case of weak tunneling, t = 0:01m eV. In both cases the rst electron traverses the molecule with spin up (red region, indicated by an up arrow), given the spin-polarized nature of the ground state, for a range of V_{sd} until the rst excited state enters the conducting window and the spin polarization is reduced (blue region). At a given Vsd value, increasing V_{α} results then in a drop in the spin polarization, with possible alternations in value (as in panel (a)). A larger interdot coupling t results in a larger N = 1Coulomb diam ond, as the bonding-antibonding gap increases. The width of spin-up polarized current bands,

for the N :0! 1 transition (red regions), is given by $_{\rm z}$, as we would expect. A lso, the separation between these bands for either $\,$ xed Vg or V_{\rm sd} is simply 2t. For the spin-down polarized current, this width is approxim ately

 $_{\rm Z}$, as one can verify from the energy expressions above. For small t values, as in panel (b), successive bands of polarized current are either up or near zero polarization, indicative of the predom inant triplet states at or near the ground state. On the other hand, for t > t_{\rm c}, as in panel (a), increasing $V_{\rm g}$ results eventually in a band of down-polarized current (yellow region, indicated by a down arrow), which extends over a large region in the $V_{\rm sd}$ $V_{\rm g}$ plane. In this regime the ground state is given

by the singlet, the result of the increased hybridization of the DQD $\,$ m olecular state.

Although our calculations here are for the sets few electrons in the DQD molecule, our discussion should be valid for any relatively isolated manifold of the molecule level structure. In other words, low-lying states have zero spin (typical of any closed shell), and only states near the Fermilevelwould mix/hybridize, reproducing the regime we discuss here.

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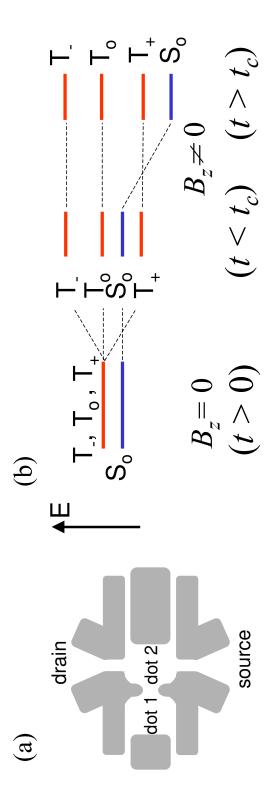


FIG. 1: (Color online) (a) Schem atic of the double quantum dot structure. Current passes bnly through' dot 2; dots are connected via a gated quantum point contact with tunneling t. (b) Low energy level structure for two electrons in a D Q D in various regimes. Notice singlet is the ground state for t> $t_{\rm c}$, as shown on right.

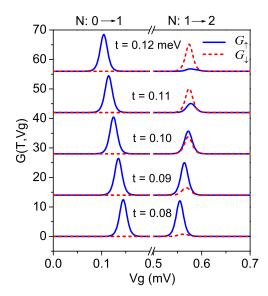


FIG. 2: (Color online) Spin-resolved conductance (in arb. units) for up (blue solid) and down (red dashed) electrons, as function of the interdot hopping amplitude t in a magnetic eld. Notice that for t > $t_{\rm c}=0.1 m~{\rm eV}$, the second (higher $V_{\rm g})$ Coulomb blockade conductance peak changes to spin-down, while the rst Coulomb blockade peak is always spin-up. This is the bipolar liter e ect. Here, $t_{\rm SO}=0.1 t.$

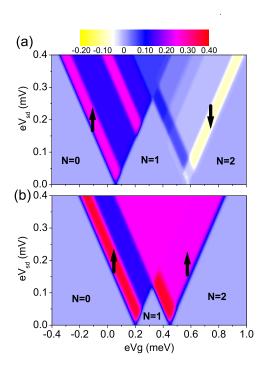


FIG. 3: (Color online) M ap of the current spin polarization (I $_{\rm I}$ I $_{\rm I}$) through a D Q D m olecule conducting through a single dot; Zeem an splitting $_{\rm Z}=0.08 {\rm m~eV}$. (a) Results for t = 0.15 m eV $_{\rm V}$ t $_{\rm C}$. Notice both bands of up (red, up arrow) and down (yellow, down arrow) spin. (b) For small interdot coupling, t = 0.01 m eV , only up spins dom inate the current at all bias and gate conditions. O ther parameters as in Fig. 2.